NSN 5961-01-319-1726

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-319-1726 **Inclosure Material:** Plastic or ceramic **Overall Length:** Between 0.570 inches and 0.620 inches **Terminal Length:** 0.500 inches **Overall Height:** Between 0.170 inches and 0.190 inches **Overall Width:** Between 0.380 inches and 0.404 inches **Function For Which Designed:** Switching **Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-22oab **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 collector to emitter voltage/static/base open and 90.0 collector to emitter voltage, dc with base short-circuited to emitter and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 6.00 amperes source cutoff current and 0.50 amperes source cutoff current **Power Rating Per Characteristic:** 30.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**